

Study on SiPM breakdown voltage, dark current and gain from room temperature down to 50 K

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Introduction

Silicon Photo-Multipliers (SiPMs) at cryogenic temperatures are very promising for the realization of scintillation light detectors to be adopted in particle physics experiments dedicated to neutrino and Dark Matter searches. For these reasons, we tested several devices from different manufacturers with particular emphasis to breakdown voltage, dark current and gain changes at different temperatures. The system, based on a cryo-pump with a cold head, permits to scan the temperature from 300 K down to 50 K. A second system, based on a climatic chamber, was also used. We found that the breakdown voltage decreases with the temperature with a typical coefficient. Furthermore, the thermal component of the noise decreases at low temperature, thus allowing the use of the device at higher overvoltage.

Experimental apparatus

Two different experimental set-up have been used:

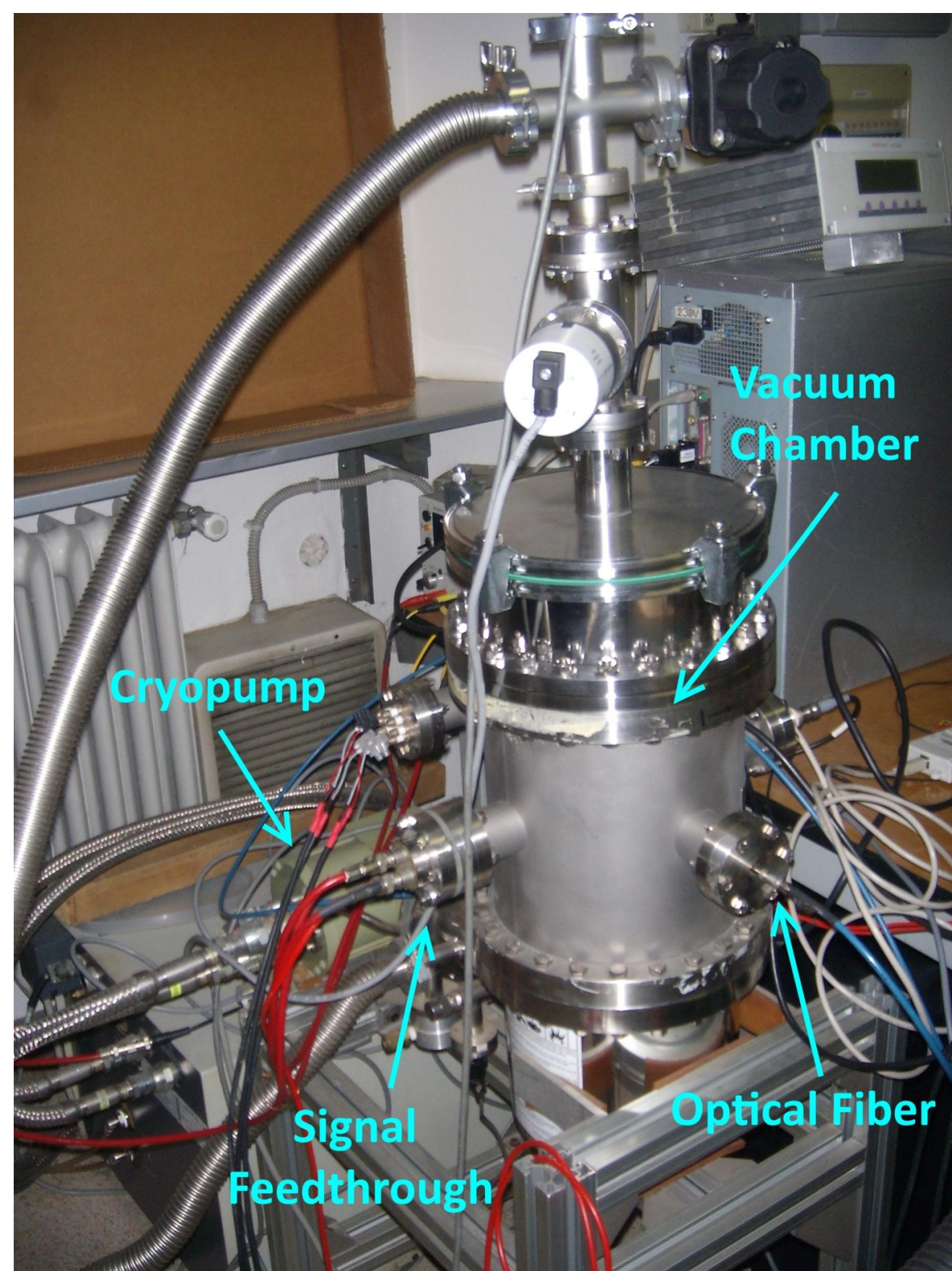


Fig. 1: picture of the first experimental apparatus.

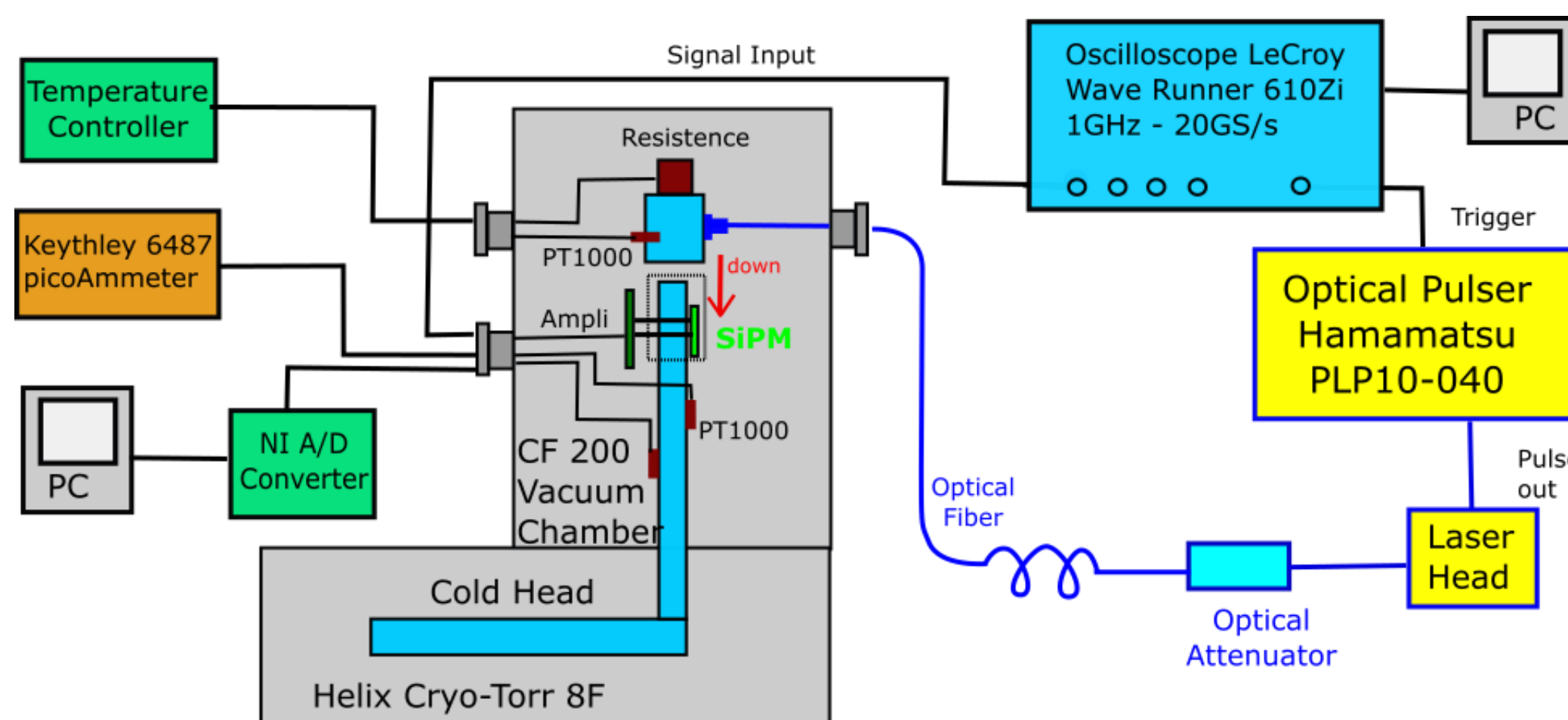


Fig. 2: sketch of the first experimental set-up.



The second setup consists of a Climatic chamber (F.lli Gallii model Genviro-030LC) with a temperature range from -60°C to +60°C that houses the SiPM to be tested.

The inner part of the chamber can be connected to the external world by means of electrical and optical (optical fiber) feedthrough. A picoAmmeter is used to apply the voltage to the SiPM and to measure the current.

An Hamamatsu PLP10-040, with an emission wavelength at 405 nm, pulse width of 60 ps (FWHM) and peak power of 200mW is used to illuminate the device.

Signals are acquired by means of a LeCroy digital Oscilloscope.

Fig.3: Climatic Chamber.

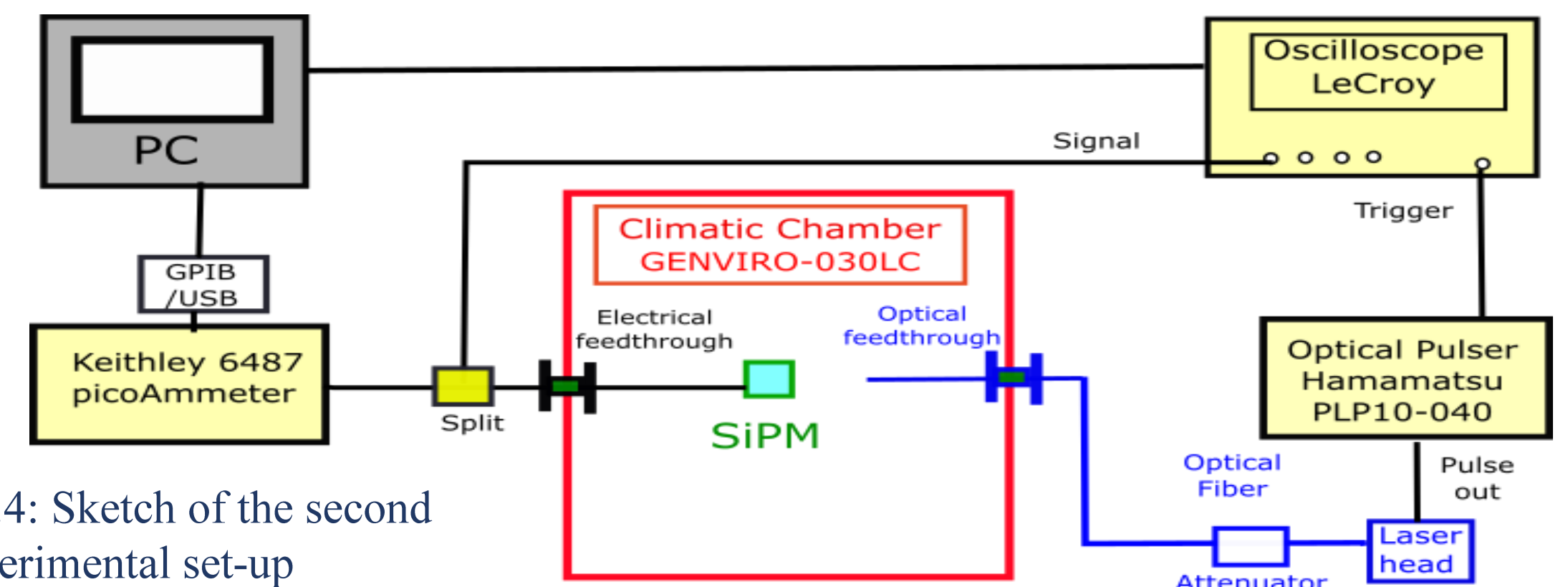


Fig.4: Sketch of the second experimental set-up

Devices under test

We decided to test some 3x3mm² SiliconPM produced by Hamamatsu (model S12512 and S13360), and AdvanSiD (model ASD-NUV3S-P and ADS-RGB3S-P) and the new VUV4 2x2 array, 6x6 mm² each from Hamamatsu. A picture of tested devices is presented in Fig. 5.

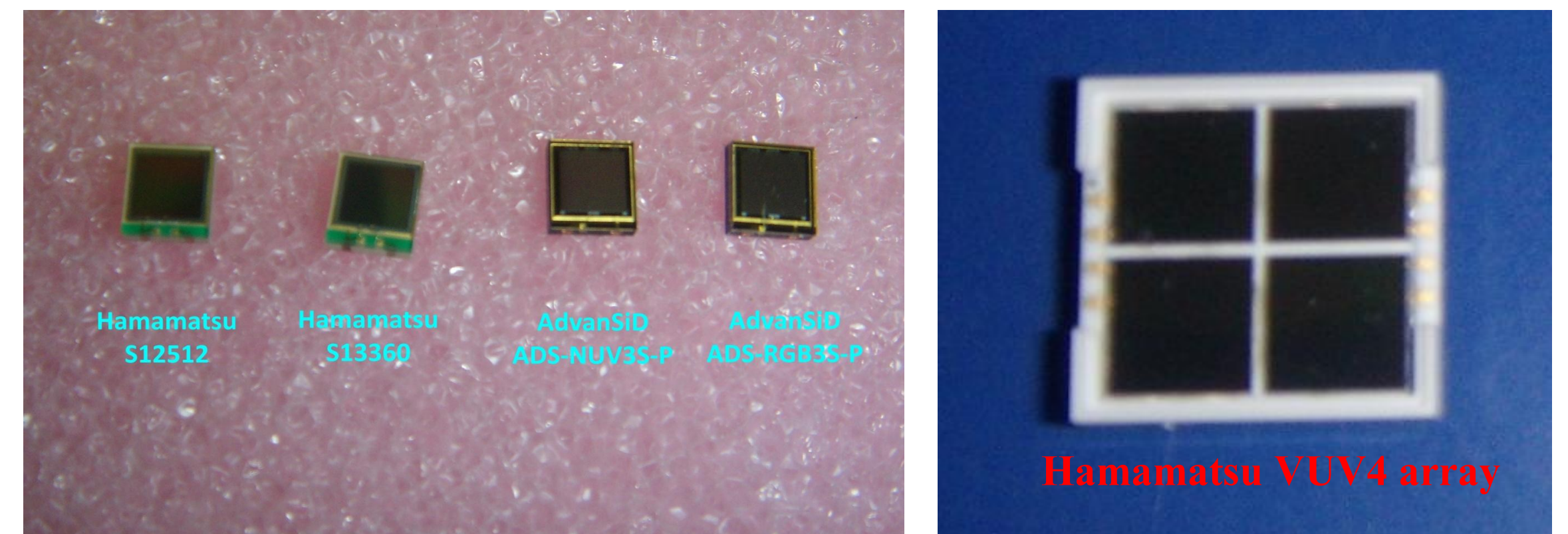


Fig. 5. Picture of tested devices.

Results

A number of tests has been carried out on the above devices. Here the preliminary results are shown in terms of I-V curves, breakdown voltage, dark current and gain:

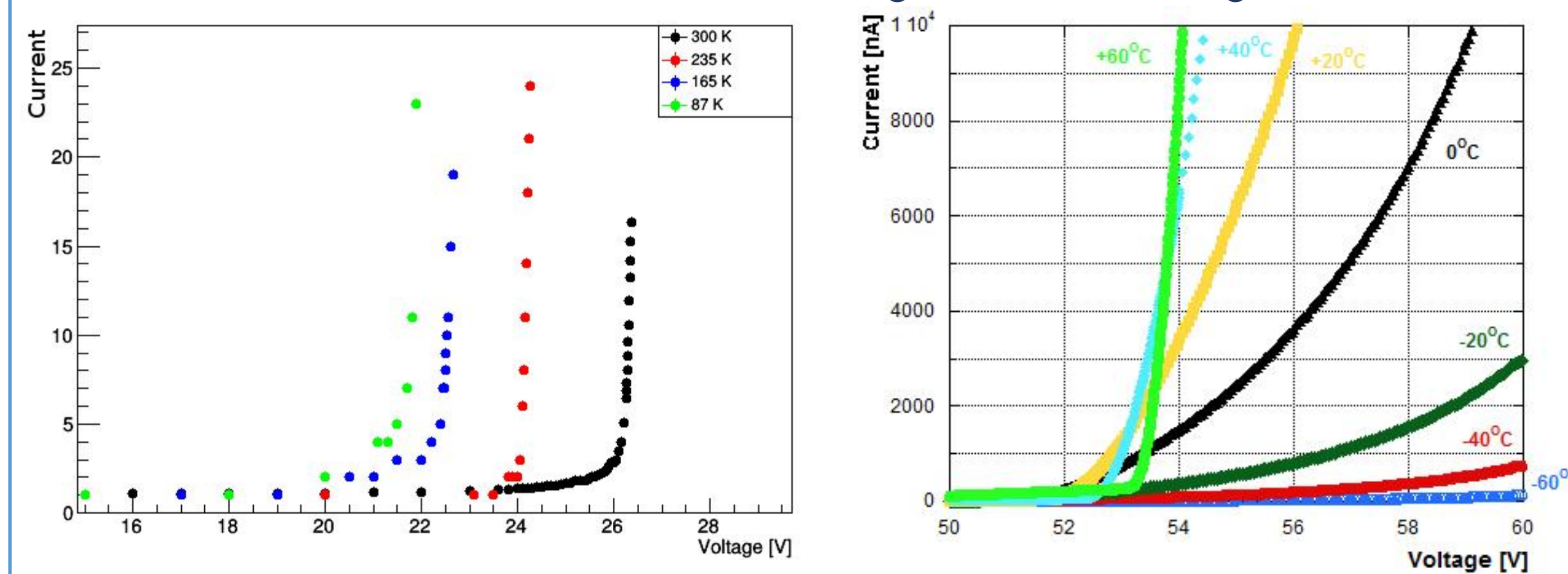


Fig. 6 : I-V curves at different temperatures. Left: AdvanSiD NUV. Right: Hamamatsu VUV4.

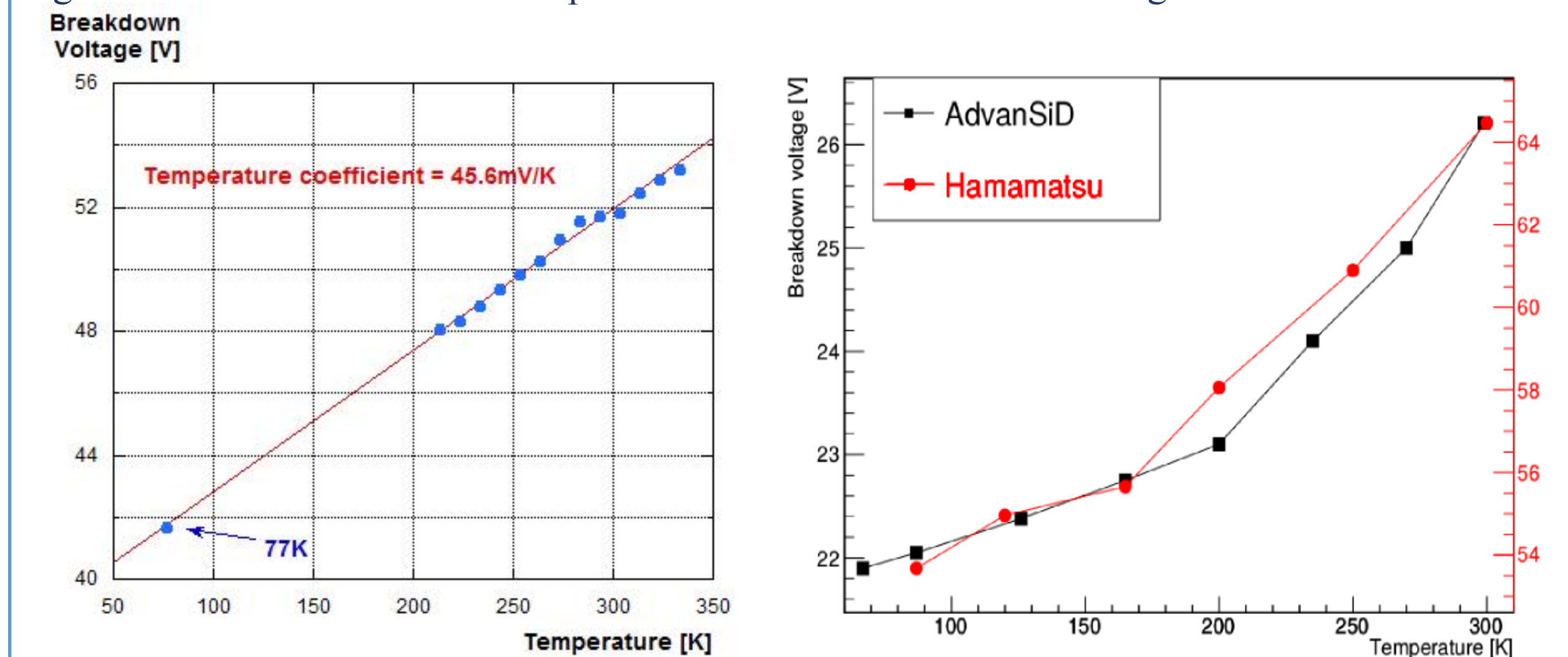


Fig. 7: BD voltage vs. T. Left: Hamamatsu VUV4. Right: AdvanSiD and Hamamatsu 3 x 3mm²

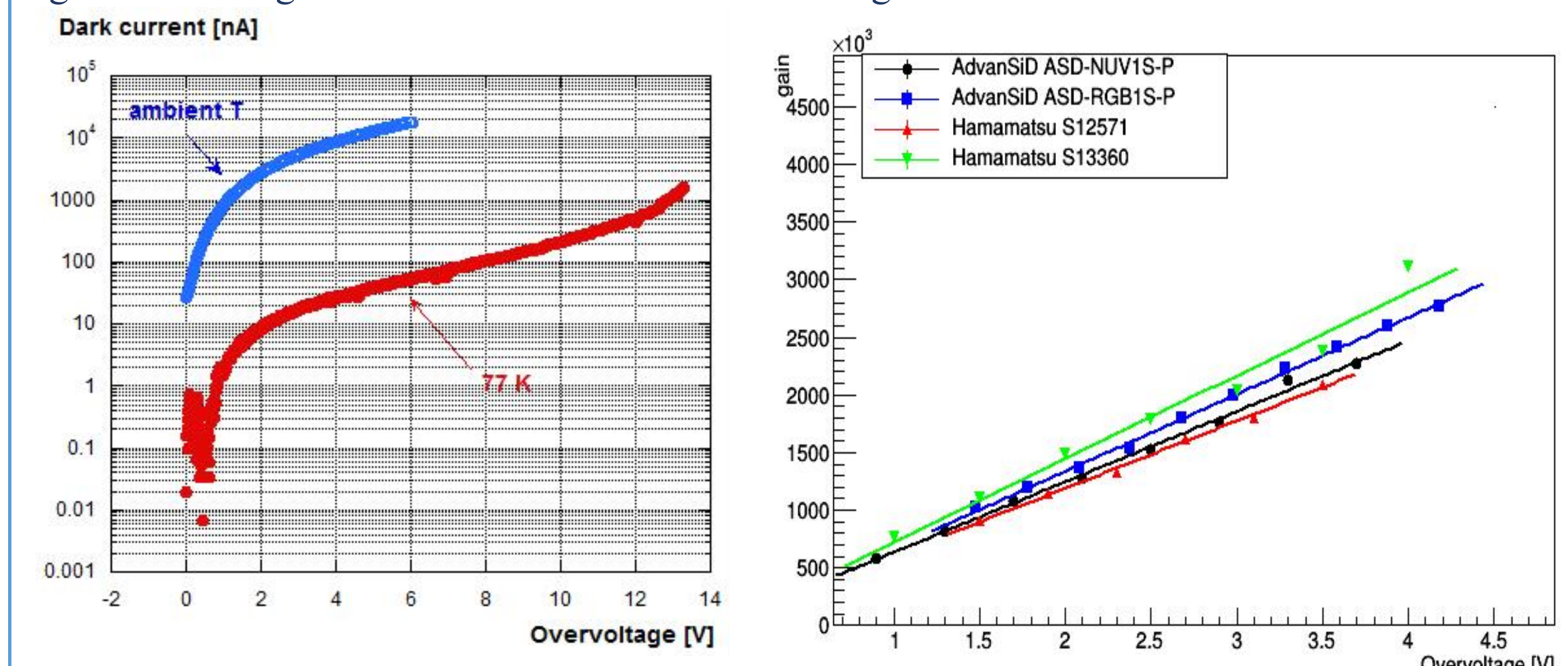


Fig. 8: dark current of Hamamatsu VUV4 at room temp. and at 77 K as noise measurement.

Fig. 9: gain at 87K for AdvanSiD and Hamamatsu 3 x 3mm²

Conclusions

These SiPM arrays have good performances in terms of breakdown voltage, dark current and gain once tested in cryogenic conditions. Therefore, they are suitable to be used for novel design scintillation light detectors dedicated to future neutrino and Dark Matter experiments.